

N-Channel 30-V (D-S) Fast Switching MOSFET

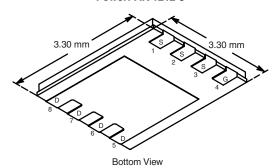
PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
30	0.0185 at V _{GS} = 10 V	10		
	0.030 at V _{GS} = 4.5 V	8		

FEATURES Halogen-fre

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFET
- New Low Thermal Resistance PowerPAK[®]
 Package with Low 1.07 mm Profile
- 100 % R_g Tested



PowerPAK 1212-8

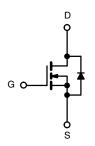


Ordering Information: Si7804DN-T1-E3 (Lead (Pb)-free)

Si7804DN-T1-GE3 (Lead (Pb)-free and Halogen-free)

APPLICATIONS

DC/DC Conversion



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	s otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	30		V	
Gate-Source Voltage		V_{GS}	± 20			
Continuous Drain Comment /T 450 90\8	T _A = 25 °C	I _D	10	6.5		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		7.5	5.0		
Pulsed Drain Current		I _{DM}	40		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.2		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	15 11			
Avalanche Energy	L = 0.1 mn	E _{AS}			mJ	
W	T _A = 25 °C	P _D	3.5	1.5	W	
Maximum Power Dissipation ^a	T _A = 70 °C		1.9	0.8		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		00	
Soldering Recommendations (Peak Temperature) ^{b, c}			260		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manimum lumation to Ambrianta	t ≤ 10 s	- R _{thJA}	28	35	°C/W
Maximum Junction-to-Ambient ^a	Steady State		65	81	
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	4.5	6.0	

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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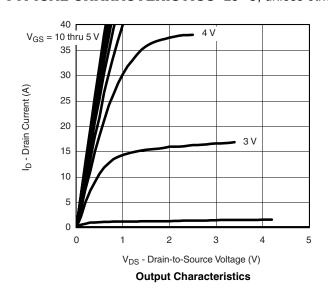
MOSFET SPECIFICATIONS $T_J = 25$ °C, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.8		1.8	V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V$, $V_{GS} = \pm 20 V$			± 100	nA		
Zoro Cata Valtaga Drain Current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V		1	μΑ			
Zero Gate Voltage Drain Current		V _{DS} = 30 V, V _{GS} = 0 V, T _J = 55 °C	= 55 °C 5					
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α		
	В	V _{GS} = 10 V, I _D = 10 A	V _{GS} = 10 V, I _D = 10 A		0.0185	0		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 8 A		0.022	0.030	Ω		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 10 A		16		S		
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.75	1.2	V		
Dynamic ^b								
Total Gate Charge	Qg			8.7	13	nC		
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 10 \text{ A}$		1.5				
Gate-Drain Charge	Q_{gd}			3.5				
Gate Resistance	R_g		0.5	1.4	2.2	Ω		
Turn-On Delay Time	t _{d(on)}			8	15			
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		12	20			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		32	50	ns		
Fall Time	t _f			14	25			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, dI/dt = 100 A/μs		30	60			

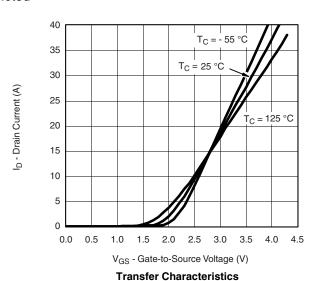
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



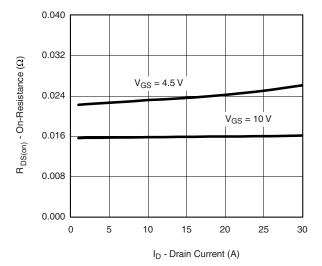




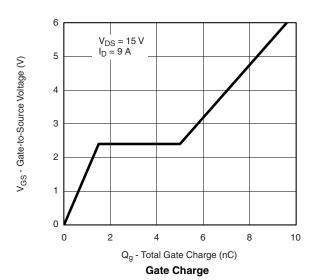


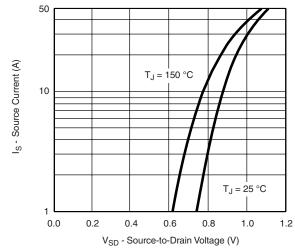


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

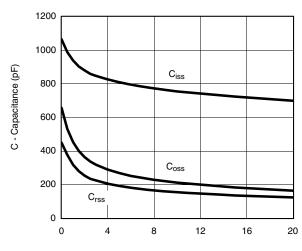


On-Resistance vs. Drain Current



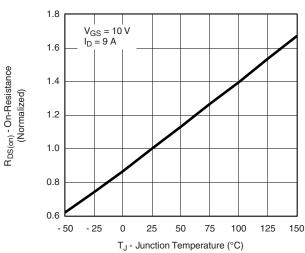


Source-Drain Diode Forward Voltage

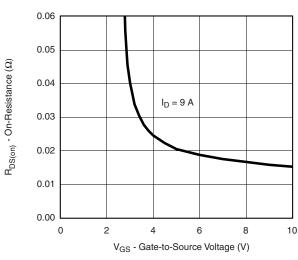


V_{DS} - Drain-to-Source Voltage (V)





On-Resistance vs. Junction Temperature

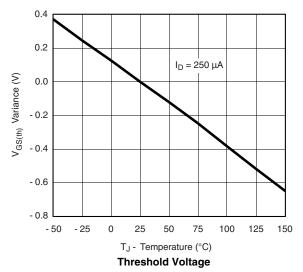


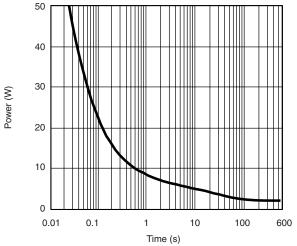
On-Resistance vs. Gate-to-Source Voltage

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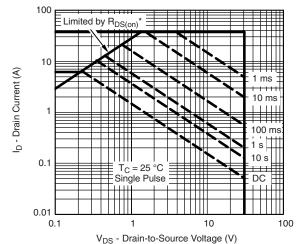
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



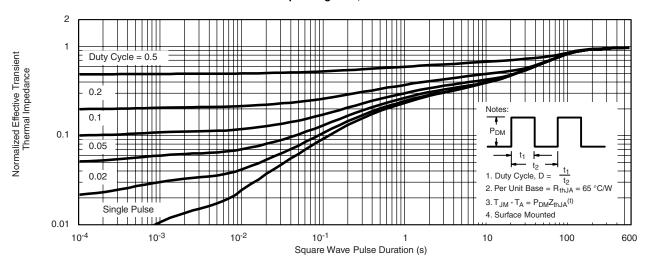


Single Pulse Power, Junction-to-Ambient



* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

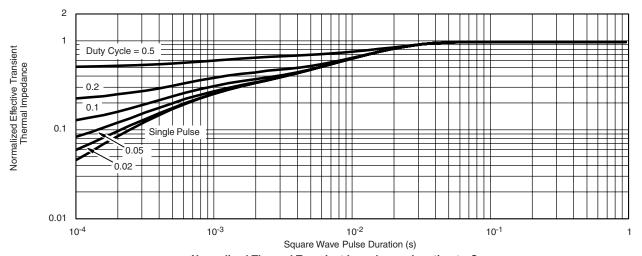
Safe Operating Area, Junction-to-Foot



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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